

SMS05C, SMS12C, SMS15C, SMS24C

5-Line Transient Voltage Suppressor Array

This 5-line voltage transient suppressor array is designed for application requiring transient voltage protection capability. It is intended for use in over-transient voltage and ESD sensitive equipment such as computers, printers, automotive electronics, networking communication and other applications. This device features a monolithic common anode design which protects five independent lines in a single SC-74 package.

Features

- Protects up to 5 Lines in a Single SC-74 Package
- Peak Power Dissipation – 350 W ($8 \times 20 \mu\text{s}$ Waveform)
- ESD Rating of Class 3B (Exceeding 8.0 kV) per Human Body Model and Class C (Exceeding 400 V) per Machine Model
- Compliance with IEC 61000-4-2 (ESD) 15 kV (Air), 8.0 kV (Contact)
- Flammability Rating of UL 94 V-0
- These are Pb-Free Devices

Applications

- Hand-Held Portable Applications
- Networking and Telecom
- Automotive Electronics
- Serial and Parallel Ports
- Notebooks, Desktops, Servers

MAXIMUM RATINGS ($T_J = 25^\circ\text{C}$ unless otherwise specified)

Symbol	Rating	Value	Unit
$P_{PK} 1$	Peak Power Dissipation $8 \times 20 \mu\text{s}$ Double Exponential Waveform (Note 1)	350	W
T_J	Operating Junction Temperature Range	-40 to 150	$^\circ\text{C}$
T_{STG}	Storage Temperature Range	-55 to 150	$^\circ\text{C}$
T_L	Lead Solder Temperature (10 s)	260	$^\circ\text{C}$
ESD	Human Body Model (HBM) Machine Model (MM) IEC 61000-4-2 Air (ESD) IEC 61000-4-2 Contact (ESD)	>8000 >400 >15000 >8000	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Non-repetitive current pulse per Figure 3.

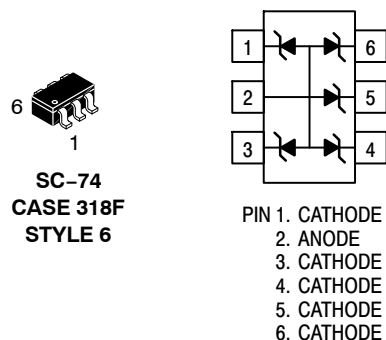


ON Semiconductor®

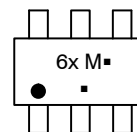
<http://onsemi.com>

SC-74 FIVE TRANSIENT VOLTAGE SUPPRESSOR 350 W PEAK POWER

PIN ASSIGNMENT



MARKING DIAGRAM



x = SMS05C:J
= SMS12C:K
= SMS15C:L
= SMS24C:M
M = Date Code
▪ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping†
SMS05CT1G	SC-74 (Pb-Free)	3000/Tape & Reel
SMS12CT1G		
SMS15CT1G		
SMS24CT1G		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

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SMS05C ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reverse Working Voltage	V _{RWM}	(Note 2)			5.0	V
Breakdown Voltage	V _{BR}	I _T = 1.0 mA (Note 3)	6.2		7.2	V
Reverse Leakage Current	I _R	V _{RWM} = 5.0 V			5.0	μA
Clamping Voltage	V _C	I _{PP} = 5.0 A (8 × 20 μs Waveform)			9.8	V
Clamping Voltage	V _C	I _{PP} = 24 A (8 × 20 μs Waveform)			14.5	V
Maximum Peak Pulse Current	I _{PP}	8 × 20 μs Waveform			24	A
Capacitance	C _J	V _R = 0 V, f = 1.0 MHz (Line to GND)		260	400	pF

SMS12C ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reverse Working Voltage	V _{RWM}	(Note 2)			12	V
Breakdown Voltage	V _{BR}	I _T = 1.0 mA (Note 3)	13.3		15	V
Reverse Leakage Current	I _R	V _{RWM} = 12 V		0.001	1.0	μA
Clamping Voltage	V _C	I _{PP} = 5.0 A (8 × 20 μs Waveform)			19	V
Clamping Voltage	V _C	I _{PP} = 15 A (8 × 20 μs Waveform)			23	V
Maximum Peak Pulse Current	I _{PP}	8 × 20 μs Waveform			15	A
Capacitance	C _J	V _R = 0 V, f = 1.0 MHz (Line to GND)		120	150	pF

SMS15C ELECTRICAL CHARACTERISTICS (T_J = 25°C, unless otherwise specified) (See Note 4)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reverse Working Voltage	V _{RWM}	(Note 2)			15	V
Breakdown Voltage	V _{BR}	I _T = 1.0 mA (Note 3)	17		19	V
Reverse Leakage Current	I _R	V _{RWM} = 15 V		0.05	1.0	μA
Clamping Voltage	V _C	I _{PP} = 5.0 A (8 × 20 μs Waveform)			24	V
Clamping Voltage	V _C	I _{PP} = 12 A (8 × 20 μs Waveform)			29	V
Maximum Peak Pulse Current	I _{PP}	8 × 20 μs Waveform			12	A
Capacitance	C _J	V _R = 0 V, f = 1.0 MHz (Line to GND)		95	125	pF

SMS24C ELECTRICAL CHARACTERISTICS (T_J = 25°C, unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reverse Working Voltage	V _{RWM}	(Note 2)			24	V
Breakdown Voltage	V _{BR}	I _T = 1.0 mA (Note 3)	26.7		32	V
Reverse Leakage Current	I _R	V _{RWM} = 24 V		0.001	1.0	μA
Clamping Voltage	V _C	I _{PP} = 5.0 A (8 × 20 μs Waveform)			40	V
Clamping Voltage	V _C	I _{PP} = 8 A (8 × 20 μs Waveform)			44	V
Maximum Peak Pulse Current	I _{PP}	8 × 20 μs Waveform			8.0	A
Capacitance	C _J	V _R = 0 V, f = 1.0 MHz (Line to GND)		60	75	pF

2. TVS devices are normally selected according to the working peak reverse voltage (V_{RWM}), which should be equal or greater than the DC or continuous peak operating voltage level.
3. V_{BR} is measured at pulse test current I_T.
4. Parametrics are the same for the Pb-Free packages, which are suffixed with a "G".

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[查询"SMS05C-D"供应商](#)

TYPICAL PERFORMANCE CURVES ($T_J = 25^\circ\text{C}$ unless otherwise specified)

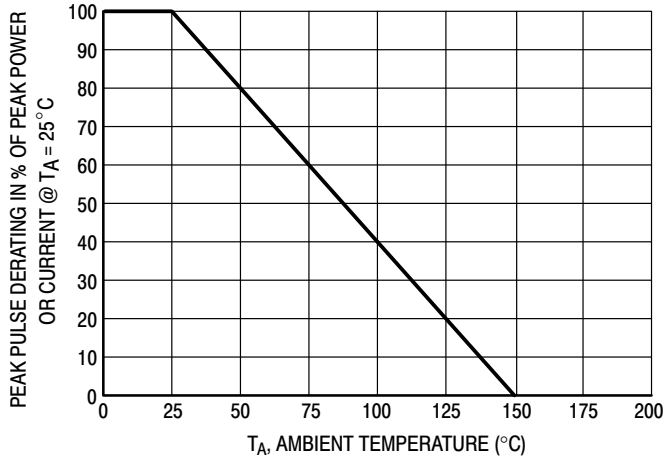


Figure 1. Pulse Derating Curve

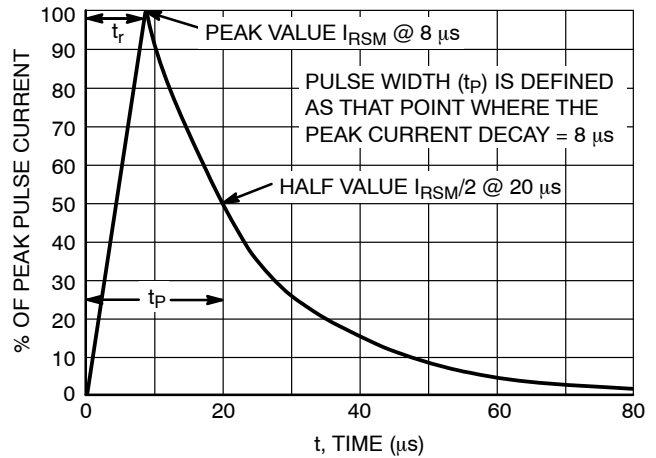


Figure 2. $8 \times 20 \mu\text{s}$ Pulse Waveform

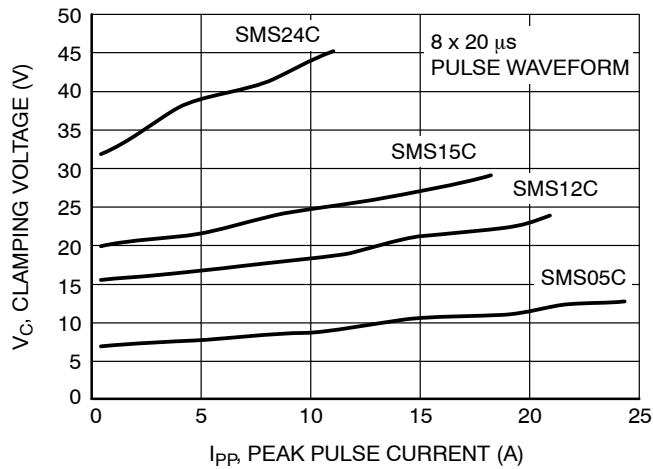


Figure 3. Clamping Voltage vs. Peak Pulse Current

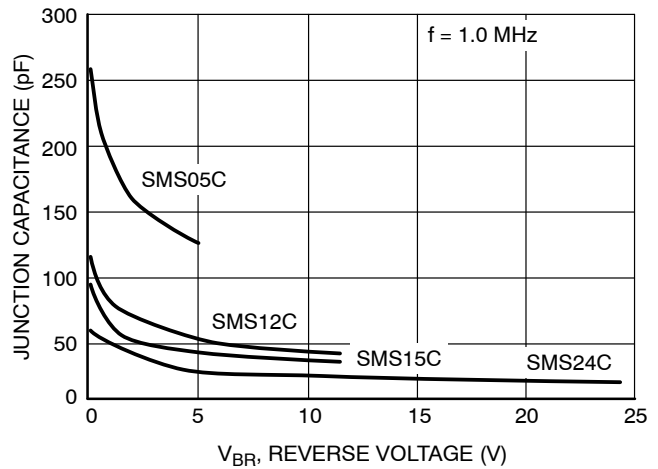
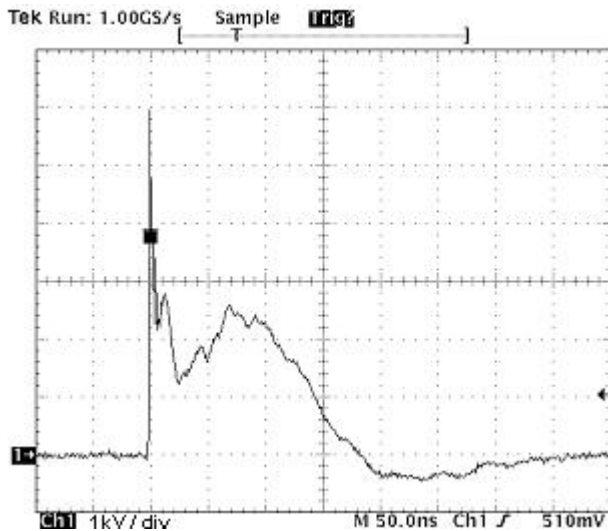
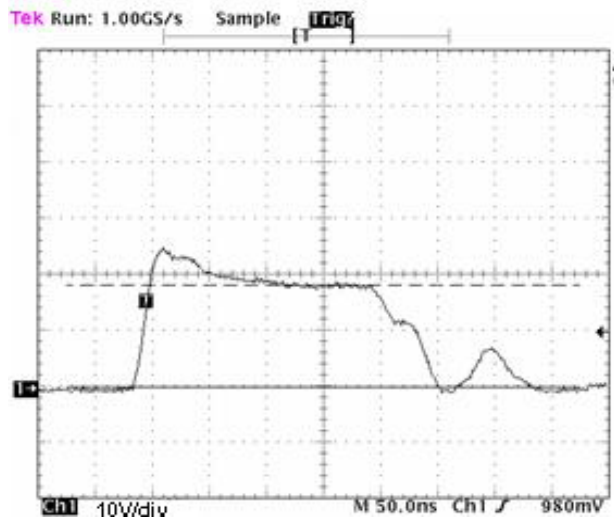


Figure 4. Junction Capacitance vs. Reverse Voltage



**Figure 5. ESD Pulse IEC 61000-4-2
(8.0 kV Contact)**



**Figure 6. SMS15CT1 ESD Response for IEC
61000-4-2 (+8.0 kV Contact)**

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TYPICAL COMMON ANODE APPLICATIONS

A 5 TVS junction common anode design in a SC-74 package protects four separate lines using only one package. This adds flexibility and creativity to PCB design especially

when board space is at a premium. A simplified example of SMS05C Series Device applications is illustrated below.

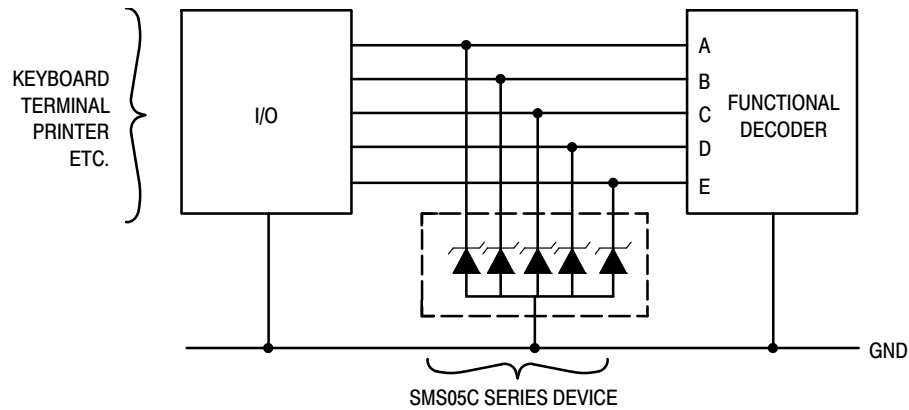


Figure 7. Computer Interface Protection

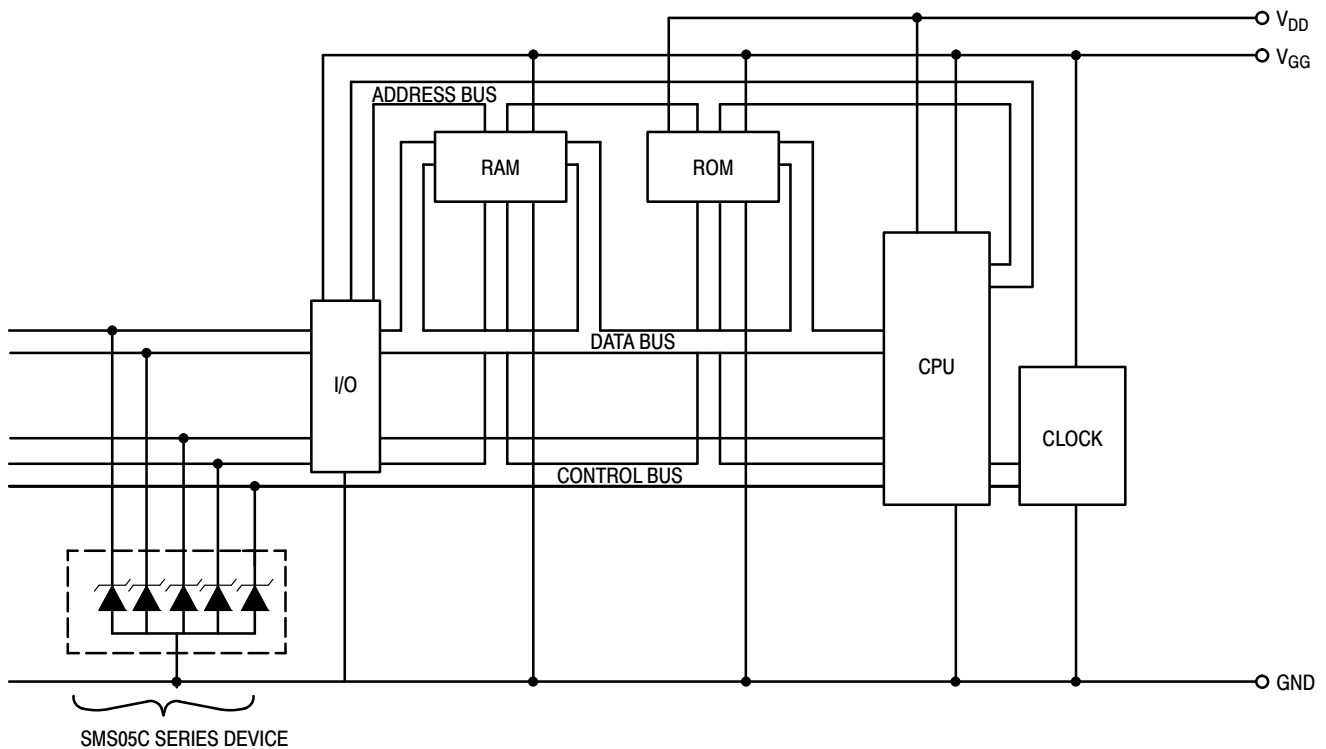


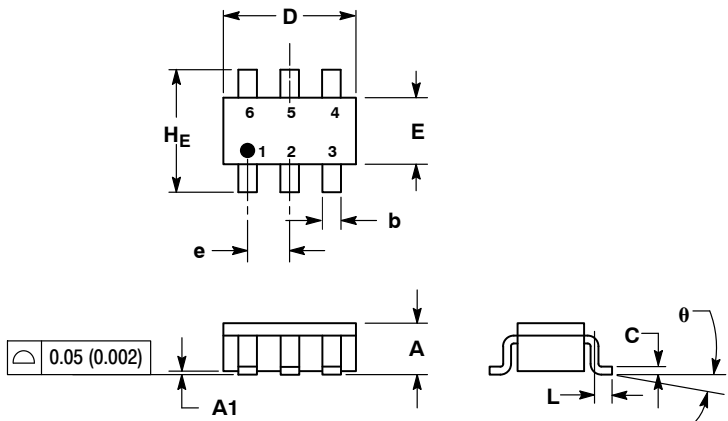
Figure 8. Microprocessor Protection

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PACKAGE DIMENSIONS

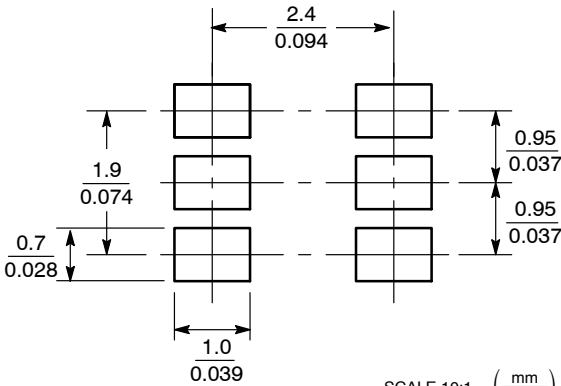
SC-74
CASE 318F-05
ISSUE M



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
 4. 318F-01, -02, -03, -04 OBSOLETE. NEW STANDARD 318F-05.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.90	1.00	1.10	0.035	0.039	0.043
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.25	0.37	0.50	0.010	0.015	0.020
c	0.10	0.18	0.26	0.004	0.007	0.010
D	2.90	3.00	3.10	0.114	0.118	0.122
E	1.30	1.50	1.70	0.051	0.059	0.067
e	0.85	0.95	1.05	0.034	0.037	0.041
L	0.20	0.40	0.60	0.008	0.016	0.024
HE	2.50	2.75	3.00	0.099	0.108	0.118
θ	0°	—	10°	0°	—	10°

SOLDERING FOOTPRINT*



STYLE 6:
PIN 1. CATHODE
2. ANODE
3. CATHODE
4. CATHODE
5. CATHODE
6. CATHODE

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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